# **DSA5G01**

## Silicon PNP epitaxial planar type

For high-frequency amplification DSA2G01 in SMini3 type package

#### ■ Features

- High transition frequency f<sub>T</sub>
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)

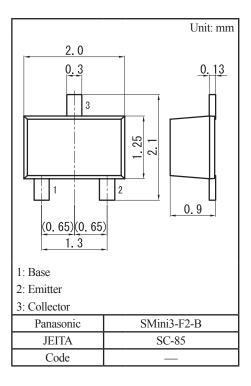
#### ■ Marking Symbol: A4

#### Packaging

DSA5G01×0L Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	-30	V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	-20	V
Emitter-base voltage (Collector open)	$V_{EBO}$	-5	V
Collector current	$I_{C}$	-30	mA
Collector power dissipation	P <sub>C</sub>	150	mW
Junction temperature	T <sub>j</sub>	150	°C
Operating ambient temperature	T <sub>opr</sub>	-40 to +85	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C



### ■ Electrical Characteristics $T_a = 25$ °C±3°C

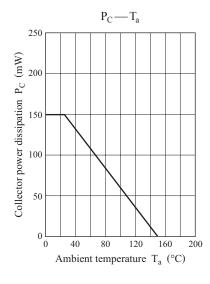
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Base-emitter voltage	$V_{\mathrm{BE}}$	$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$		-0.7		V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = -10 \text{ V}, I_{E} = 0$			-0.1	μА
Collector-emitter cutoff current (Base open)	I <sub>CEO</sub>	$V_{CE} = -20 \text{ V}, I_{B} = 0$			-100	μА
Emitter-base cutoff current (Collector open)	$I_{EBO}$	$V_{EB} = -5 \text{ V}, I_C = 0$			-10	μА
Forward current transfer ratio *1	$h_{\mathrm{FE}}$	$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$	70		220	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = -10 \text{ mA}, I_{\rm B} = -1 \text{ mA}$		-0.1		V
Transition frequency	$f_T$	$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$	150	300		MHz
Reverse transfer capacitance (Common emitter)	C <sub>re</sub>	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ mA}, f = 10.7 \text{ MHz}$		1.0		pF
Noise figure	NF	$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}, f = 5 \text{ MHz}$		2.8		dB
Reverse transfer impedance	$Z_{rb}$	$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}, f = 2 \text{ MHz}$		22		Ω

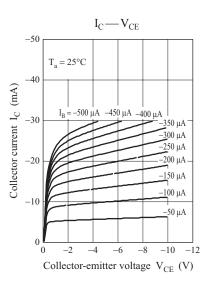
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

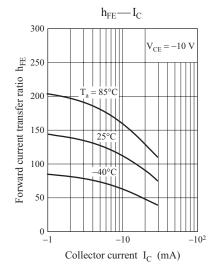
#### 2. \*1: Rank classification

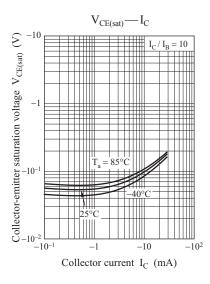
Code	В	С	0	
Rank	В	С	No-rank	
$h_{\mathrm{FE}}$	70 to 140	110 to 220	70 to 220	
Marking Symbol	A4B	A4C	A4	

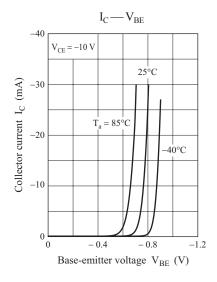
Product of no-rank is not classified and have no marking symbol for rank.

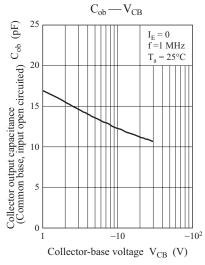


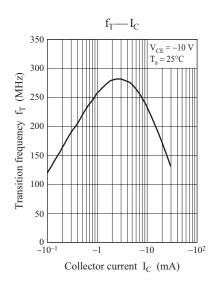








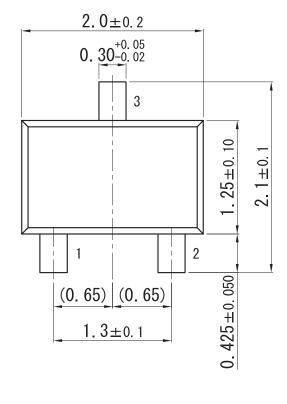


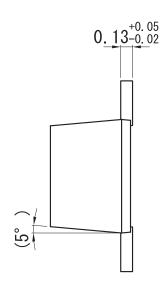


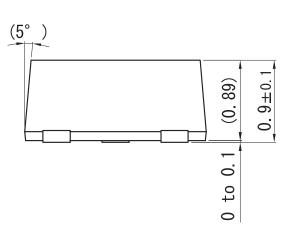
Ver. CED 2

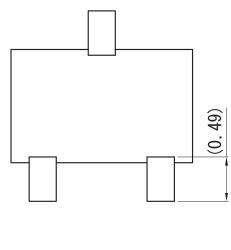
# SMini3-F2-B

Unit: mm

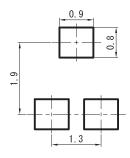








### ■ Land Pattern (Reference) (Unit: mm)



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